

Mosfet, p, reel 1k

Manufacturers	Infineon Technologies Corporation
Package/Case	SOT223
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for BSP171PL6327 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

BSP171PL6327 is a specific type of Field-Effect Transistor (FET) manufactured by Infineon Technologies. Here are some of its features:

Features

It has a maximum drain-source voltage of 50V

It has a maximum continuous drain current of 140mA

It has a low threshold voltage of 1V

It has a low on-resistance of 2.2 Ohms

Application

BSS138LT1G

2N7002DW

AO3400A

SI2302DS-T1-E3

BS170NL



Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



[BSC011N03LS](#)

Infineon Technologies Corporation
PG-TDSON-8



[BSB013NE2LXI](#)

Infineon Technologies Corporation
WDSO-N-2



[BSC014N04LSATMA1](#)

Infineon Technologies Corporation
tdson-8



[BSC030N08NS5ATMA1](#)

Infineon Technologies Corporation
TDSON-8



[BSC026N08NS5ATMA1](#)

Infineon Technologies Corporation
TDSON-8



[BSC016N06NSATMA1](#)

Infineon Technologies Corporation
DSO-N-8



[BSC066N06NSATMA1](#)

Infineon Technologies Corporation
TDSON-8